

AUG 2,4 2007, 1449

## LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT

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SERIAL NO.	ATTORNEY DOCKET NO.		
09/872,381	2807.2.19		
FILING DATE	GROUP ART UNIT		
June 1, 2001	2878		
APPLICANT(S): John N. Hai	t et al.		

## REFERENCE DESIGNATION U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS/ SUBCLASS	FILING DATE
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EXAMINER Drums	Éia~	DATE CONSIDERED	5/28/2004

PTO/SB/08A (08-00)

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Complete if Known					
Application Number 09/872381					
Filing Date	8/2/2001 RECEIVED				
First Named Inventor	Hait JUL 2 9 2002				
Group Art Unit	Technology Contactor				
Examiner Name	Technology Center 2600				
Attorney Docket Number	2807.2.19.0				

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Examiner Initials*	Cite No.1	U.S. Patent	t Document Kind Code <sup>2</sup> (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
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<sup>&</sup>lt;sup>1</sup>Unique citation designation number. <sup>2</sup>See attached Kinds of U.S. Patent Documents. <sup>3</sup>Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup>For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup>Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup>Applicant is to place a check mark here if English language Translation is attached.

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